6MBI50FA-060 (50A)

IGBT MODULE (F series)

Features

- Low Saturation Voltage
- Voltage Drive
- All Screw Terminals for Automated Assembly

Applications

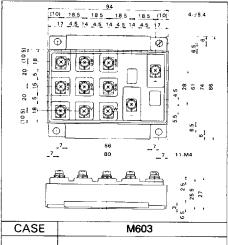
- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial Machines, such as Welding Machines

Maximum Ratings and Characteristics

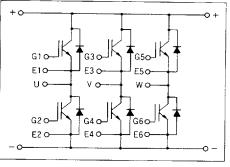
Absolute Maximum Ratings

ltems		Symbols	Ratings	Units	
Collecter-Emitter Voltage		VCES	600	V	
Gate-Emi	tter Voltage	Vges	±20	V	
Collecter Current	Continuous	lc	50	+	
	1ms	IC pulse	100		
	Continuous	-lc	50	A	
	1ms	-IC pulse	100	1	
Max. Powe	ver Dissipation Pc		220	W	
Operating	Temperature	Tj	+150	°C	
Storage T	Storage Temperature		-40 to +125	°C	
Isolation Voltage	AC. 1min.	Vis	2500	v	
Screw Torque		Mounting *1	3.5 {35}	N•m	
		Terminals *2	1.7 {17}	{kg.cm	

Outline Drawings



Equivalent Circuit Schematic



*1 Recommendable Value 2.5 to 3.5 N*m 25 to 35 kg*cm (M5) *2 Recommendable Value 1.3 to 1.7 N*m 13 to 17 kg*cm (M4)

Electrical Characteristics (Tc=25°C)

ltems	Symbols	Test Conditions	Min.	Тур.	Max.	Units
Zero Gate Voltage Collecter Current	ICES	VGE=0V VCE=600V Tj=25°C			1.0	mA
		VGE=0V VCE=600V Tj=125°C				mA
Gate-Emitter Leackage Current	IGES	VCE=0V VGE=±20V			100	nA
Gate-Emitter Threshold Voltage	VGE (th)	Vce=20V lc=50mA	3.0		6.0	V
Collecter-Emitter Saturation Voltage	VCE (sat)	VGE=15V IC=50A			2.5	v
Input Capacitance	Cies	Vge=0V		4750		
Output Capacitance	Coes	Vce=10V				۶q
Reverse Transfer Capacitance	Cres	f=1MHz				
Turn-on Time Resistive load	ton	Vcc=300V			0.8	μs
	tr	Ic=50A			0.6	
Turn-off Time Inductive load	toff	VGE=±15V			1.5	
	tr	Rg=51Ω			1.0	
Diode Forward On-Voltage	VF	IF=50A, VGE=0V			2.5	V
Reverse Recovery Time	trr	IF=50A, -di/dt=150A/µs VGE=-10V			300	ns

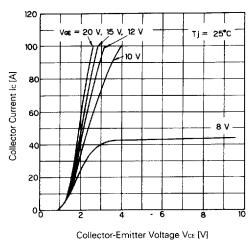
Thermal Characteristics

ltems	Symbols	Test Conditions	Min.	Тур.	Max.	Units
Thermal Resistance	Rth (j–c)	IGBT			0.568	°C/W
	Rth (j-c)	Diode			1.33	
	Rth (c-f)	With Thermal compound		0.05		

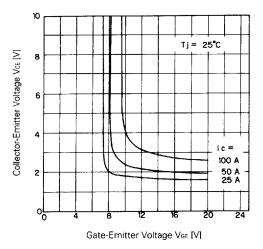
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Collector Current vs. Collector-Emitter Voltage



Collector-Emitter Voltage vs. Gate-Emitter Voltage

300 V ±15 V 51 Ω

toff

tf

ton

tr

50

60

Vcc Voe Ro Ti

20

10

1

10

10

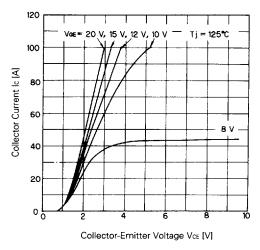
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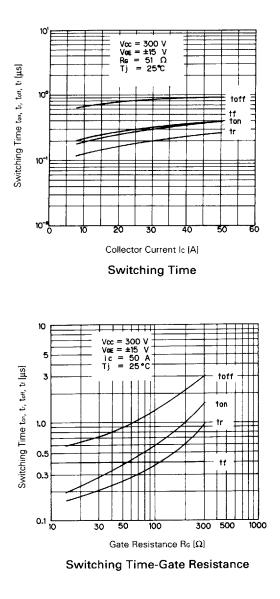
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Switching Time ton, tr, tott, tf [µs]

82



Collector Current vs. Collector-Emitter Voltage



30

Collector Current Ic [A]

Switching Time

40

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